

**GreenPAK** <sup>™</sup>

FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

### **General Description**

Renesas SLG7RN46384 is a low power and small form device. The SoC is housed in a 2mm x 3mm STQFN package which is optimal for using with small devices.

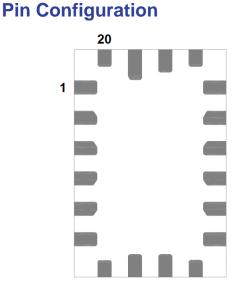
### **Features**

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 20 Package

### **Output Summary**

1 Output - Push Pull 1X

7 Outputs - Push Pull 2X



20-pin STQFN (Top View)

### **Pin name**

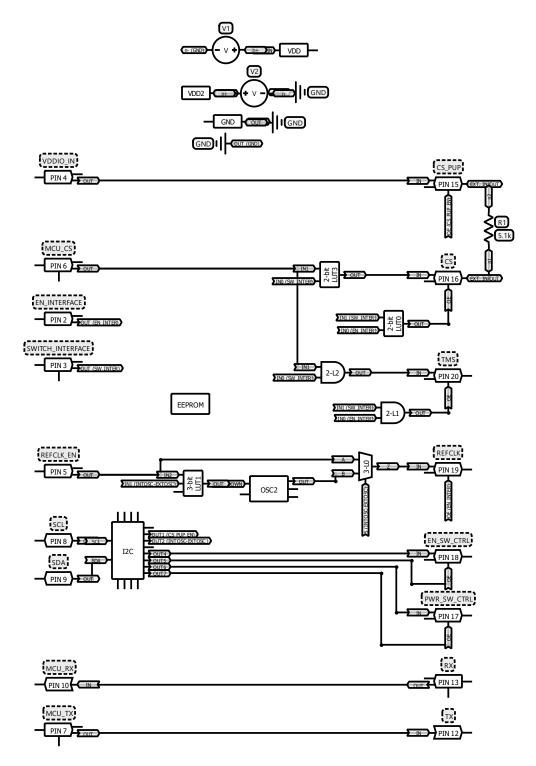
Pin #	Pin name	Pin #	Pin name
1	VDD	11	GND
2	EN_INTERFACE	12	ТХ
3	SWITCH_INTERFACE	13	RX
4	VDDIO_IN	14	VDD2
5	REFCLK_EN	15	CS_PUP
6	MCU_CS	16	CS
7	MCU_TX	17	PWR_SW_CTRL
8	SCL	18	EN_SW_CTRL
9	SDA	19	REFCLK
10	MCU_RX	20	TMS





FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

## **Block Diagram**





FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

	0		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
Pin	$(: \cap$	ntia	uration
		''''y	anation

Pin #	Pin Name	Туре	Pin Description	Internal Resistor
1	VDD	PWR	Supply Voltage	
2	EN_INTERFACE	Digital Input	Digital Input without Schmitt trigger	10kΩ pulldown
3	SWITCH_INTERFACE	Digital Input	Digital Input without Schmitt trigger	10kΩ pulldown
4	VDDIO_IN	Digital Input	Low Voltage Digital Input	$1M\Omega$ pulldown
5	REFCLK_EN	Digital Input	Digital Input without Schmitt trigger	floating
6	MCU_CS	Digital Input	Digital Input without Schmitt trigger	floating
7	MCU_TX	Digital Input	Digital Input without Schmitt trigger	floating
8	SCL	Digital Input	Digital Input without Schmitt trigger	floating
9	SDA	Digital Input	Digital Input without Schmitt trigger	floating
10	MCU_RX	Digital Output	Push Pull 1X	floating
11	GND	GND	Ground	
12	ТΧ	Digital Output	Push Pull 2X	floating
13	RX	Digital Input	Digital Input without Schmitt trigger	100kΩ pulldown
14	VDD2	PWR	Supply Voltage	
15	CS_PUP	Bi-directional	Digital Input without Schmitt trigger / Push Pull 2X	floating
16	CS	Bi-directional	Digital Input without Schmitt trigger / Push Pull 2X	floating
17	PWR_SW_CTRL	<b>Bi-directional</b>	Digital Input without Schmitt trigger / Push Pull 2X	floating
18	EN_SW_CTRL	Bi-directional	Digital Input without Schmitt trigger / Push Pull 2X	floating
19	REFCLK	<b>Bi-directional</b>	Digital Input without Schmitt trigger / Push Pull 2X	floating
20	TMS	<b>Bi-directional</b>	Digital Input without Schmitt trigger / Push Pull 2X	floating

## **Ordering Information**

Part Number	Package Type
SLG7RN46384V	20-pin STQFN
SLG7RN46384V	20-pin STQFN - Tape and Reel (3k units)





FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

### **Absolute Maximum Conditions**

Parameter	Min.	Max.	Unit	
Vhigh to GND	-0.3	7	V	
Voltage at Input Pin		GND-0.5V	VDD+0.5V	V
Maximum Average or DC Current Three	ough V <sub>DD</sub> Pin		90	mA
Maximum Average or DC Current Thro	ugh V <sub>DD2</sub> Pin		90	mA
Maximum Average or DC Current Thro (Per chip side, (Note 1))		100	mA	
Maximum Average or DC Current	Push-Pull 1x		15.3	mA
(Through pin)	Push-Pull 2x		22.1	ША
Current at Input Pin		-1.0	1.0	mA
Input leakage (Absolute Val	le)		1000	nA
Storage Temperature Rang	je	-65	150	°C
Junction Temperature			150	°C
ESD Protection (Human Body M	/lodel)	2000		V
ESD Protection (Charged Device	1300		V	
Moisture Sensitivity Level	1	1		
Note 1 The GreenPAK's GND rail is divident one side and IOs 7 to 14 are connected		IOs 0 to 6, SCL	., SDA are conne	ected to

## **Electrical Characteristics**

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
V <sub>DD</sub>	Supply Voltage		5	5	5	V
$V_{DD2}$	Supply Voltage		5	5	5	V
TA	Operating Temperature		-40	25	85	°C
$C_{VDD}$	Capacitor Value at VDD			0.1		μF
CIN	Input Capacitance			4		pF
la	Quiescent Current	Static inputs and floating outputs PIN8 and PIN9 are HIGH PINs 5 – 7, 15 – 20 are LOW		380		μA
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD+0.3	V
Maria	HIGH-Level Input Voltage	Logic Input	0.7xVDD		VDD+0.3	V
Vін	(Note 1)	Low-Level Logic Input	1.25		VDD+0.3	V
Ma	LOW-Level Input Voltage	Logic Input	GND-0.3		0.3xVDD	V
VIL	(Note 1)	Low-Level Logic Input	GND-0.3		0.5	V
N/	HIGH-Level Output Voltage	Push-Pull 1X, I <sub>OH</sub> =5mA at VDD=5.0V	4.678			V
Vон	(Note 1)	Push-Pull 2X, I <sub>OH</sub> =5mA at VDD=5.0V	4.821			V
M	LOW-Level Output Voltage	Push-Pull 1X, IoL=5mA, at VDD=5.0V			0.256	V
Vol	(Note 1)	Push-Pull 2X, IoL=5mA, at VDD=5.0V			0.145	V
1	HIGH-Level Output Current	Push-Pull 1X, VOH=2.4V at VDD=5.0V	25.12			mA
Іон	(Note 1)	Push-Pull 2X, VOH=2.4V at VDD=5.0V	48.49			mA





# FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

Iol Rpull_down Tsu PONthr	LOW-Level Output Current	Push-Pull 1X, V <sub>OL</sub> =0.4V, at VDD=5.0V	7.67			mA
	(Note 1)	Push-Pull 2X, V <sub>OL</sub> =0.4V, at VDD=5.0V	13.52			mA
	Pull down on PINs 2, 3			10		kΩ
	Internal Pull Down Resistance (Note 1)	Pull down on PIN 13		100		kΩ
		Pull down on PIN 4		1		MΩ
Ts∪	Startup Time	From VDD rising past PONTHR		1.66	2.59	ms
PONTHR	Power On Threshold	V <sub>DD</sub> Level Required to Start Up the Chip	1.60	1.85	2.07	V
POFFTHR	Power Off Threshold	V <sub>DD</sub> Level Required to Switch Off the Chip	0.97	1.23	1.46	V
Note:						

note:

1. PINs 1 to 10 are powered from VDD and PINs 12 to 20 are powered from VDD2.

2. Guaranteed by Design.

## **I<sup>2</sup>C Specifications**

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
Fscl	Clock Frequency, SCL	V <sub>DD</sub> = (2.35.5) V			400	kHz
t∟ow	Clock Pulse Width Low	V <sub>DD</sub> = (2.35.5) V	1300			ns
tніgн	Clock Pulse Width High	V <sub>DD</sub> = (2.35.5) V	600			ns
tı	Input Filter Spike Suppression (SCL, SDA)	V <sub>DD</sub> = (2.35.5) V			95	ns
taa	Clock Low to Data Out Valid	V <sub>DD</sub> = (2.35.5) V			900	ns
tBUF	Bus Free Time between Stop and Start	V <sub>DD</sub> = (2.35.5) V	1300			ns
t <sub>hd_sta</sub>	Start Hold Time	V <sub>DD</sub> = (2.35.5) V	600			ns
t <sub>su_sta</sub>	Start Set-up Time	V <sub>DD</sub> = (2.35.5) V	600			ns
t <sub>hd_dat</sub>	Data Hold Time	V <sub>DD</sub> = (2.35.5) V	0			ns
t <sub>su_dat</sub>	Data Set-up Time	V <sub>DD</sub> = (2.35.5) V	100			ns
t <sub>R</sub>	Inputs Rise Time	V <sub>DD</sub> = (2.35.5) V			300	ns
t <sub>F</sub>	Inputs Fall Time	V <sub>DD</sub> = (2.35.5) V			300	ns
t <sub>su_sto</sub>	Stop Set-up Time	V <sub>DD</sub> = (2.35.5) V	600			ns
t <sub>DH</sub>	Data Out Hold Time	V <sub>DD</sub> = (2.35.5) V	50			ns

## **Chip address**

HEX	BIN	DEC
0x70	1110000	112





### **I2C Description**

#### 1. I2C Basic Command Structure

Each command to the I2C Serial Communications block begins with a Control Byte. The bits inside this Control Byte are shown in Figure 1. After the Start bit, the first four bits are a control code, which can be set by the user in reg<1623:1620>. The Block Address is the next three bits (A10, A9, A8), which will define the most significant bits in the addressing of the data to be read ("1") or written ("0") by the command. This Control Byte will be followed by an Acknowledge bit (ACK).

With the exception of the Current Address Read command, all commands will have the Control Byte followed by the Word Address. The Word Address, in conjunction with the three address bits in the Control Byte, will define the specific data byte to be read or written in the command. Figure 1 shows this basic command structure.

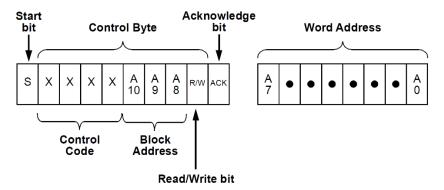


Figure 1. I2C Basic Command Structure

#### 2. I2C Serial General Timing

Shown in Figure 2 is the general timing characteristics for the I2C Serial Communications block.

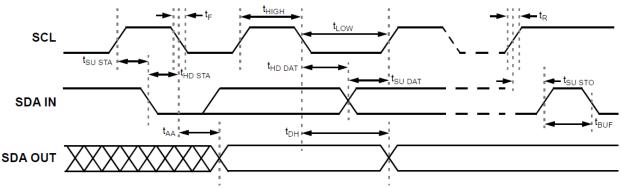


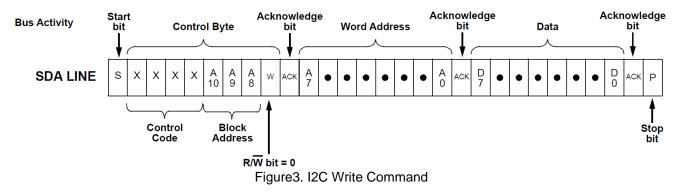
Figure 2. I2C Serial General Timing





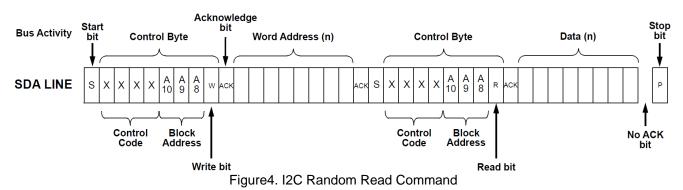
#### 3. I2C Serial Communications: Read and Write Commands

Following the Start condition from the master, the Control Code [4 bits], the block address [3 bits] and the R/W bit (set to "0"), is placed onto the bus by the Bus Master. After the I2C Serial Communications block has provided an Acknowledge bit (ACK) the next byte transmitted by the master is the Word Address. The Block Address is the next three bits, and is the higher order addressing bits (A10, A9, A8), which when added to the Word Address will together set the internal address pointer in the SLG7RN46384 to the correct data byte to be written. After the SLG7RN46384 sends another Acknowledge bit, the Bus Master will transmit the data byte to be written into the addressed memory location. The SLG7RN46384 again provides an Acknowledge bit and then the Bus Master generates a Stop condition. The internal write cycle for the data will take place at the time that the SLG7RN46384 generates the Acknowledge bit.



The Random Read command starts with a Control Byte (with  $R/\overline{W}$  bit set to "0", indicating a write command) and Word Address to set the internal byte address, followed by a Start bit, and then the Control Byte for the read (exactly the same as the Byte Write command). The Start bit in the middle of the command will halt the decoding of a Write command, but will set the internal address counter in preparation for the second half of the command. After the Start bit, the Bus

Master issues a second control byte with the  $R/\overline{W}$  bit set to "1", after which the SLG7RN46384 issues an Acknowledge bit, followed by the requested eight data bits.



#### 4. Chip reconfiguration

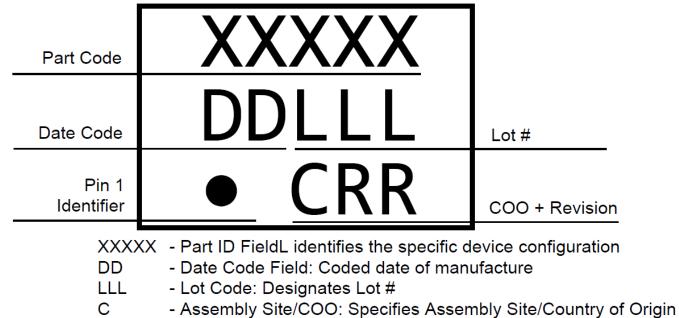
SLG7RN46384 has an ISP capability. This means that the chip internal blocks configuration may be changed on the fly or even re-programmed via I2C. If there is a need for temporary change of the chip configuration (it will be reset to the programmed configuration after the chip is reset or powered ON again) one should use Registers (A10, A9, A8 = "000"). To reprogram a configuration via I2C NVM should be accessed with A10, A9, A8 = "010". Please keep in mind that random byte write procedure is not supported, this may lead to incorrect chip configuration. Only page write procedure is supported.





FFPGADMOR2.0\_U6\_LVLSHFT2\_0x70\_R1.0

## Package Top Marking



RR - Revision Code: Device Revision

Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Revision	Date
0.11	001	U	0x97551618	46384	AA	03/22/2023

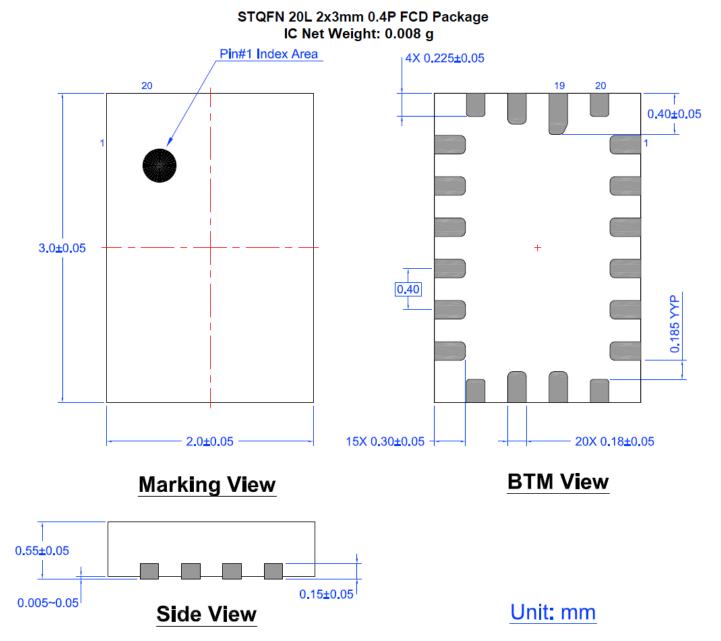
Lock coverage for this part is indicated by  $\sqrt{}$ , from one of the following options:

 Unlocked
Partly lock read
Partly lock write
Partly lock read and write
Partly lock read and lock write
Lock read and partly lock write
Read lock
Write lock
Lock read and write

The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.



## **Package Outlines**







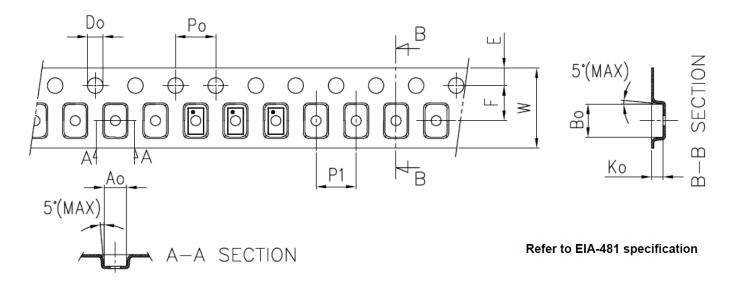
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### **Tape and Reel Specification**

•		Nominal Package Size [mm]	Max Units		Reel & Hub	Leader (min)		Trailer (min)		Таре	Part
	# of Pins		per Reel	per Box	Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 20L 2x3mm 0.4P FCD	20	2 x 3 x 0.55	3000	3000	178 / 60	100	400	100	400	8	4

## **Carrier Tape Drawing and Dimensions**

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	B0	K0	P0	P1	D0	E	F	W
STQFN 20L 2x3mm 0.4P FCD	2.2	3.15	0.76	4	4	1.5	1.75	3.5	8



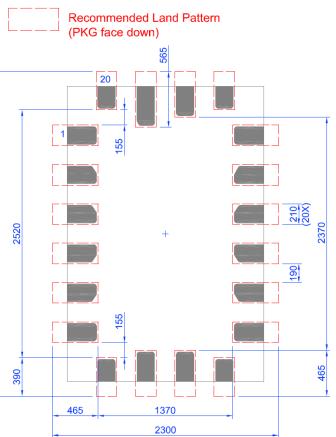
## **Recommended Reflow Soldering Profile**

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 3.30 mm<sup>3</sup> (nominal). More information can be found at <u>www.jedec.org.</u>





## **Layout Guidelines** Exposed Pad (PKG face down) 20 19 400 2520 3000 3300 400 300 (15X) 225 (4X) 390 180 (20X) 465 2000



Unit: μm





## Datasheet Revision History

Date	Version	Change
03/15/2023	0.10	New design for SLG46826 chip
03/22/2023	0.11	Updated Device Revision Table



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